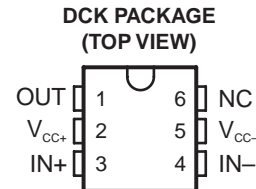
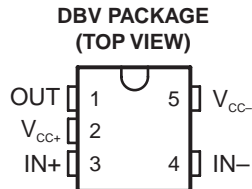
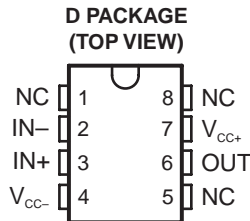


FEATURES

- Parameters Specified at 2.7-V, 5-V, and 15-V Supplies
- Supply Current 7 μ A (Typ) at 5 V
- Response Time 4 μ s (Typ) at 5 V
- Push-Pull Output
- Input Common-Mode Range Beyond V_{CC-} and V_{CC+}
- Low Input Current

APPLICATIONS

- Battery-Powered Products
- Notebooks and PDAs
- Mobile Communications
- Alarm and Security Circuits
- Direct Sensor Interface
- Replaces Amplifiers Used as Comparators With Better Performance and Lower Current



NC – No internal connection

DESCRIPTION/ORDERING INFORMATION

The TLV7211 and TLV7211A are micropower CMOS comparators available in the space-saving SOT-23-5 package. This makes the comparators ideal for space- and weight-critical designs. The TLV7211A features an input offset voltage of 5 mV, and the TLV7211 features an input offset voltage of 15 mV.

The main benefits of the SOT-23-5 package are most apparent in small portable electronic devices, such as mobile phones, pagers, notebook computers, personal digital assistants, and PCMCIA cards. The rail-to-rail input voltage makes the TLV7211 or TLV7211A a good choice for sensor interfacing, such as light detector circuits, optical and magnetic sensors, and alarm and status circuits.

The SOT-23-5 package's small size allows it to fit into tight spaces on PC boards.

ORDERING INFORMATION

T_A	V_{OS} (MAX)	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽²⁾
–40°C to 85°C	5 mV	SOIC – D	Reel of 2500	TLV7211AIDR	7211AI
			Tube of 75	TLV7211AID	
		SOT-23-5 – DBV	Reel of 3000	TLV7211AIDBVR	YBN_
		SOT (SC-70) – DCK	Reel of 3000	TLV7211AIDCKR	Y8_
			Reel of 250	TLV7211AIDCKT	
	15 mV	SOIC – D	Reel of 2500	TLV7211IDR	TY7211
			Tube of 75	TLV7211ID	
		SOT-23-5 – DBV	Reel of 3000	TLV7211IDBVR	YBK_
		SOT (SC-70) – DCK	Reel of 3000	TLV7211IDCKR	Y7_
			Reel of 250	TLV7211IDCKT	

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

(2) DBV/DCK: The actual top-side marking has one additional character that designates the assembly/test site.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

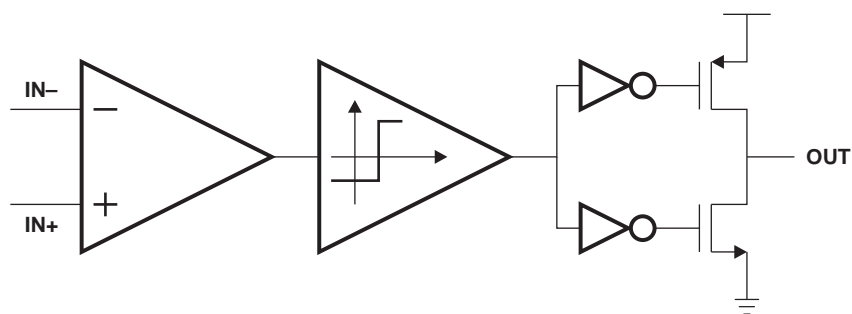
TLV7211, TLV7211A

CMOS COMPARATORS

WITH RAIL-TO-RAIL INPUT AND PUSH-PULL OUTPUT

SLCS149B – AUGUST 2006 – REVISED JANUARY 2007

FUNCTIONAL BLOCK DIAGRAM



Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
$V_{CC+} - V_{CC-}$	Supply voltage ⁽²⁾		16	V
V_{ID}	Differential input voltage ⁽³⁾		\pm Supply voltage	V
V_I	Input voltage range (any input)	$V_{CC-} - 0.3$	$V_{CC+} + 0.3$	V
V_O	Output voltage range	$V_{CC-} - 0.3$	$V_{CC+} + 0.3$	V
I_{CC}	Supply current		40	mA
I_I	Input current		± 5	mA
I_O	Output current		± 30	mA
θ_{JA}	Package thermal impedance ⁽⁴⁾⁽⁵⁾	D package	97	$^{\circ}\text{C/W}$
		DBV package	206	
		DCK package	259	
T_J	Operating virtual junction temperature		150	$^{\circ}\text{C}$
T_{stg}	Storage temperature range	-65	150	$^{\circ}\text{C}$

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values (except differential voltages and V_{CC} specified for the measurement of I_{OS}) are with respect to the network GND.
- (3) Differential voltages are at $IN+$ with respect to $IN-$.
- (4) Maximum power dissipation is a function of $T_J(\text{max})$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(\text{max}) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150 $^{\circ}\text{C}$ can affect reliability.
- (5) The package thermal impedance is calculated in accordance with JESD 51-7.

ESD Protection

	TYP	UNIT
Human-Body Model	2000	V

Recommended Operating Conditions

		MIN	MAX	UNIT
$V_{CC+} - V_{CC-}$	Supply voltage	2.7	15	V
T_J	Operating virtual junction temperature	-40	85	$^{\circ}\text{C}$

2.7-V Electrical Characteristics

$V_{CC+} = 2.7\text{ V}$, $V_{CC-} = \text{GND}$, $V_{CM} = V_O = V_{CC+}/2$, and $R_L > 1\text{ M}\Omega$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_J	TLV7211A			TLV7211			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS} Input offset voltage		25°C		3	5		3	15	mV
		–40°C to 85°C			8			18	
TCV _{OS} Input offset voltage temperature drift		25°C		1			1		µV/°C
Input offset voltage average drift ⁽¹⁾		25°C		3.3			3.3		µV/month
I_B Input current		25°C		0.04			0.04		pA
I_{OS} Input offset current		25°C		0.02			0.02		pA
CMRR Common-mode rejection ratio	$0 \leq V_{CM} \leq 2.7\text{ V}$	25°C		75			75		dB
PSRR Power-supply rejection ratio	$2.7\text{ V} \leq V_{CC+} \leq 15\text{ V}$	25°C		80			80		dB
A_V Voltage gain		25°C		100			100		dB
CMVR Input common-mode voltage range	CMRR > 55 dB	25°C	2.9	3		2.9	3		V
		–40°C to 85°C	2.7			2.7			
	CMRR > 55 dB	25°C		–0.3	–0.2		–0.3	–0.2	
		–40°C to 85°C			0			0	
V_{OH} High-level output voltage	$I_{load} = 2.5\text{ mA}$	25°C	2.4	2.5		2.4	2.5		V
		–40°C to 85°C	2.3			2.3			
V_{OL} Low-level output voltage	$I_{load} = 2.5\text{ mA}$	25°C		0.2	0.3		0.2	0.3	V
		–40°C to 85°C			0.4			0.4	
I_{CC} Supply current	$V_{OUT} = \text{Low}$	25°C		7	12		7	12	µA
		–40°C to 85°C			14			14	
	$V_{OUT} = \text{High-Idle}$	25°C		5	10		5	10	
		–40°C to 85°C			12			12	

(1) Input offset voltage average drift is calculated by dividing the accelerated operating life V_{OS} drift by the equivalent operational time. This represents worst-case input conditions and includes the first 30 days of drift.

TLV7211, TLV7211A

CMOS COMPARATORS

WITH RAIL-TO-RAIL INPUT AND PUSH-PULL OUTPUT

SLCS149B–AUGUST 2006–REVISED JANUARY 2007

5-V Electrical Characteristics

$V_{CC+} = 5\text{ V}$, $V_{CC-} = \text{GND}$, $V_{CM} = V_O = V_{CC+}/2$, and $R_L > 1\text{ M}\Omega$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_J	TLV7211A			TLV7211			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS} Input offset voltage		25°C		3	5		3	15	mV
		–40°C to 85°C			8			18	
TCV_{OS} Input offset voltage temperature drift		25°C		1			1		$\mu\text{V}/^\circ\text{C}$
Input offset voltage average drift ⁽¹⁾		25°C		3.3			3.3		$\mu\text{V}/\text{month}$
I_B Input current		25°C		0.04			0.04		pA
I_{OS} Input offset current		25°C		0.02			0.02		pA
CMRR Common-mode rejection ratio		25°C		75			75		dB
PSRR Power-supply rejection ratio	$5\text{ V} \leq V_{CC+} \leq 10\text{ V}$	25°C		80			80		dB
A_V Voltage gain		25°C		100			100		dB
CMVR Input common-mode voltage range	CMRR > 55 dB	25°C	5.2	5.3		5.2	5.3		V
		–40°C to 85°C	5			5			
	CMRR > 55 dB	25°C		–0.3	–0.2		–0.3	–0.2	
		–40°C to 85°C			0			0	
V_{OH} High-level output voltage	$I_{load} = 5\text{ mA}$	25°C	4.6	4.8		4.6	4.8		V
		–40°C to 85°C	4.45			4.45			
V_{OL} Low-level output voltage	$I_{load} = 5\text{ mA}$	25°C		0.2	0.4		0.2	0.4	V
		–40°C to 85°C			0.55			0.55	
I_{CC} Supply current	$V_{OUT} = \text{Low}$	25°C		7	14		7	14	μA
		–40°C to 85°C			18			18	
	$V_{OUT} = \text{High-Idle}$	25°C		5	10		5	10	
		–40°C to 85°C			13			13	
I_{OH} Short-circuit output current	I_{source}	25°C		30			30		mA
I_{OL} Short-circuit output current	I_{sink} , $V_O < 12\text{ V}^{(2)}$	25°C		45			45		mA

(1) Input offset voltage average drift is calculated by dividing the accelerated operating life V_{OS} drift by the equivalent operational time. This represents worst-case input conditions and includes the first 30 days of drift.

(2) Do not short circuit the output to $V+$ if $V+$ is $>12\text{ V}$.

15-V Electrical Characteristics

$V_{CC+} = 15\text{ V}$, $V_{CC-} = \text{GND}$, $V_{CM} = V_O = V_{CC+}/2$, and $R_L > 1\text{ M}\Omega$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_J	TLV7211A			TLV7211			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS} Input offset voltage		25°C		3	5		3	15	mV
		–40°C to 85°C			8			18	
TCV_{OS} Input offset voltage temperature drift		25°C		4			4		$\mu\text{V}/^\circ\text{C}$
Input offset voltage average drift ⁽¹⁾		25°C		4			4		$\mu\text{V}/\text{month}$
I_B Input current		25°C		0.04			0.04		pA
I_{OS} Input offset current		25°C		0.02			0.02		pA
CMRR Common-mode rejection ratio		25°C		82			82		dB
PSRR Power-supply rejection ratio	$5\text{ V} \leq V_{CC+} \leq 10\text{ V}$	25°C		80			80		dB
A_V Voltage gain		25°C		100			100		dB
CMVR Input common-mode voltage range	CMRR > 55 dB	25°C	15.2	15.3		15.2	15.3		V
		–40°C to 85°C	15			15			
	CMRR > 55 dB	25°C		–0.3	–0.2		–0.3	–0.2	
		–40°C to 85°C			0			0	
V_{OH} High-level output voltage	$I_{load} = 5\text{ mA}$	25°C	14.6	14.8		14.6	14.8		V
		–40°C to 85°C	14.45			14.45			
V_{OL} Low-level output voltage	$I_{load} = 5\text{ mA}$	25°C		0.2	0.4		0.2	0.4	V
		–40°C to 85°C			0.55			0.55	
I_{CC} Supply current	$V_{OUT} = \text{Low}$	25°C		7	14		7	14	μA
		–40°C to 85°C			18			18	
	$V_{OUT} = \text{High-Idle}$	25°C		5	12		5	12	
		–40°C to 85°C			14			14	
I_{OH} Short-circuit output current	I_{source}	25°C	30			30			mA
I_{OL} Short-circuit output current	I_{sink} , $V_O < 12\text{ V}^{(2)}$	25°C	45			45			mA

- (1) Input offset voltage average drift is calculated by dividing the accelerated operating life V_{OS} drift by the equivalent operational time. This represents worst-case input conditions and includes the first 30 days of drift.
- (2) Do not short circuit the output to V_+ if V_+ is $>12\text{ V}$.

TLV7211, TLV7211A

CMOS COMPARATORS

WITH RAIL-TO-RAIL INPUT AND PUSH-PULL OUTPUT

SLCS149B–AUGUST 2006–REVISED JANUARY 2007

Switching Characteristics

$T_J = 25^\circ\text{C}$, $V_{CC+} = 5\text{ V}$, $V_{CC-} = \text{GND}$, $V_{CM} = V_O = V_{CC+}/2$, and $R_L > 1\text{ M}\Omega$ (unless otherwise noted)

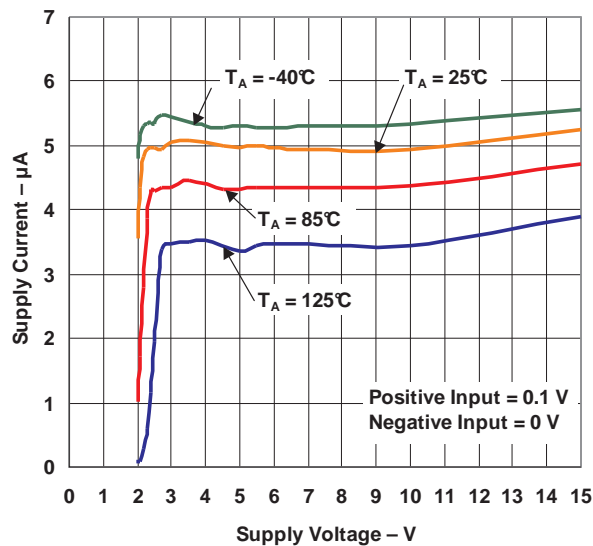
PARAMETER		TEST CONDITIONS		TYP	UNIT
t_{rise}	Rise time	$f = 10\text{ kHz}$, $C_L = 50\text{ pF}^{(1)}$, Overdrive = 10 mV		0.3	μs
t_{fall}	Fall time	$f = 10\text{ kHz}$, $C_L = 50\text{ pF}^{(1)}$, Overdrive = 10 mV		0.3	μs
t_{PHL}	Propagation delay time, high to low ⁽²⁾	$f = 10\text{ kHz}$, $C_L = 50\text{ pF}^{(1)}$	10 mV	10	μs
			100 mV	4	
		$V_{CC+} = 2.7\text{ V}$, $f = 10\text{ kHz}$, $C_L = 50\text{ pF}^{(1)}$	10 mV	10	
			100 mV	4	
t_{PLH}	Propagation delay time, low to high ⁽²⁾	$f = 10\text{ kHz}$, $C_L = 50\text{ pF}^{(1)}$	10 mV	6	μs
			100 mV	4	
		$V_{CC+} = 2.7\text{ V}$, $f = 10\text{ kHz}$, $C_L = 50\text{ pF}^{(1)}$	10 mV	7	
			100 mV	4	

(1) C_L includes probe and jig capacitance.

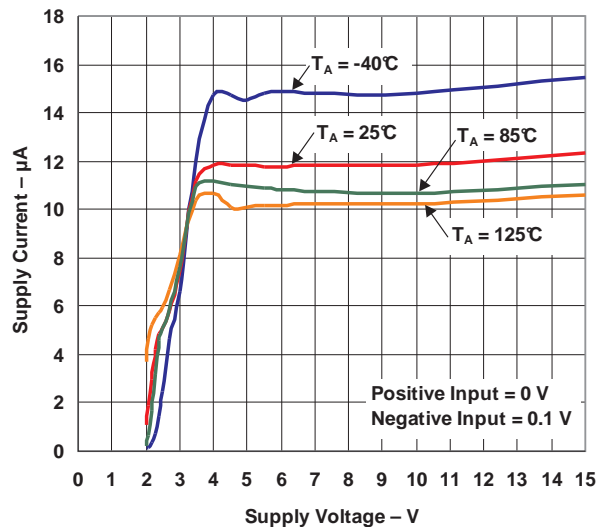
(2) Input step voltage for propagation delay measurement is 2 V.

TYPICAL CHARACTERISTICS

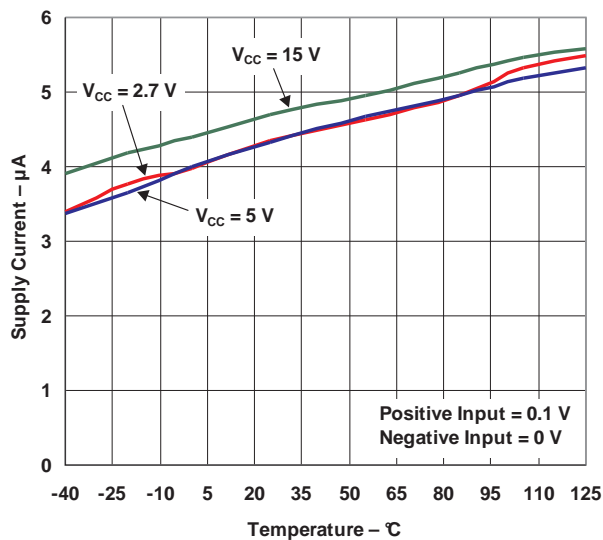
SUPPLY CURRENT
vs
SUPPLY VOLTAGE
(SOURCING)



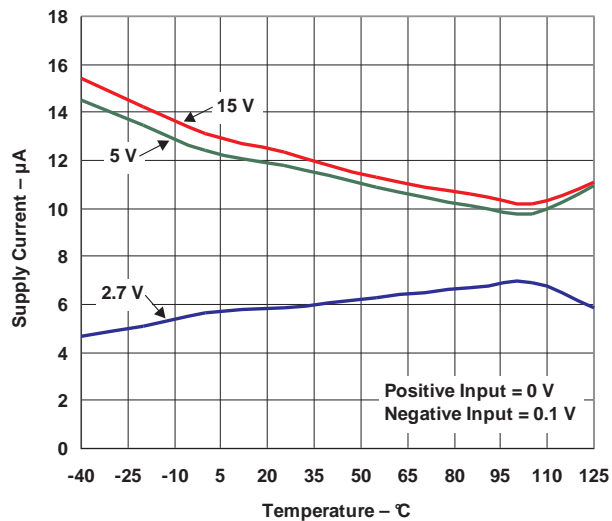
SUPPLY CURRENT
vs
SUPPLY VOLTAGE
(SINKING)



SUPPLY CURRENT
vs
TEMPERATURE
(SOURCING)

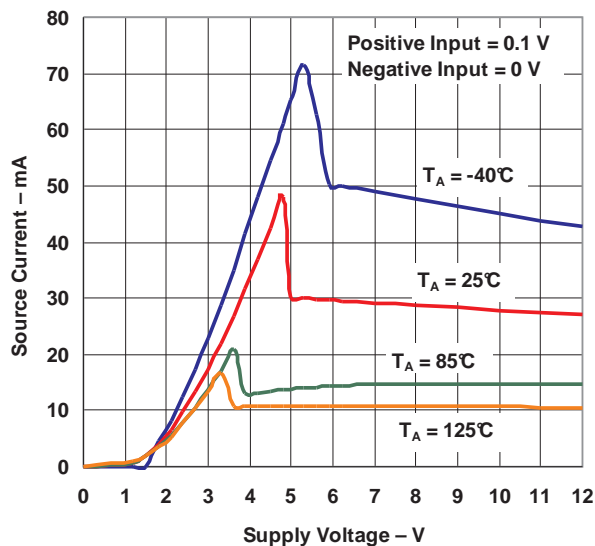


SUPPLY CURRENT
vs
TEMPERATURE
(SINKING)

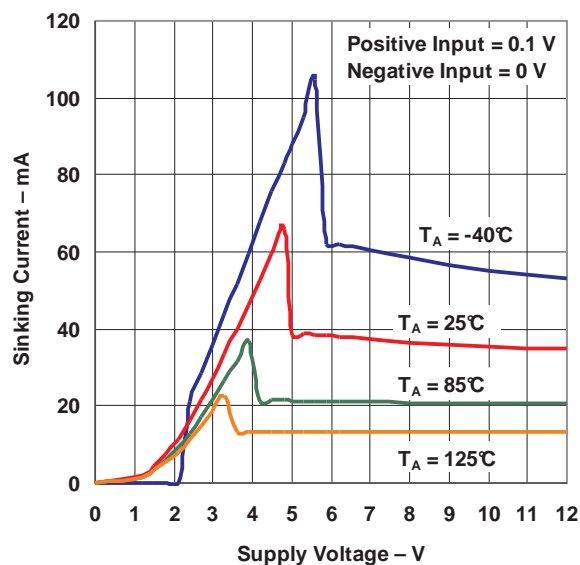


TYPICAL CHARACTERISTICS (continued)

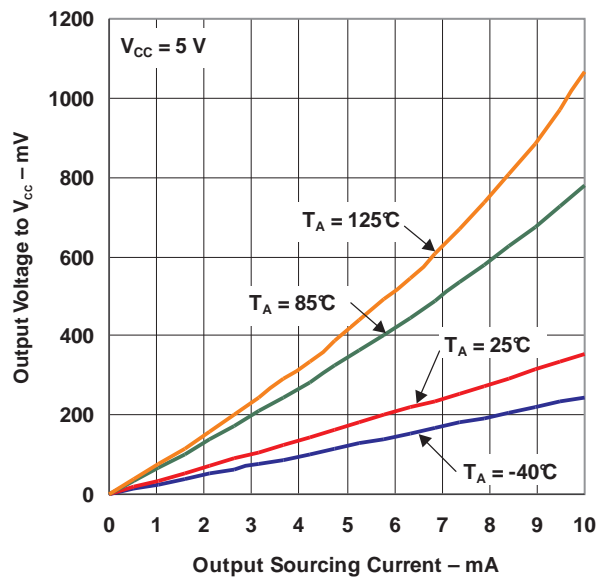
OUTPUT SOURCING CURRENT
vs
SUPPLY VOLTAGE



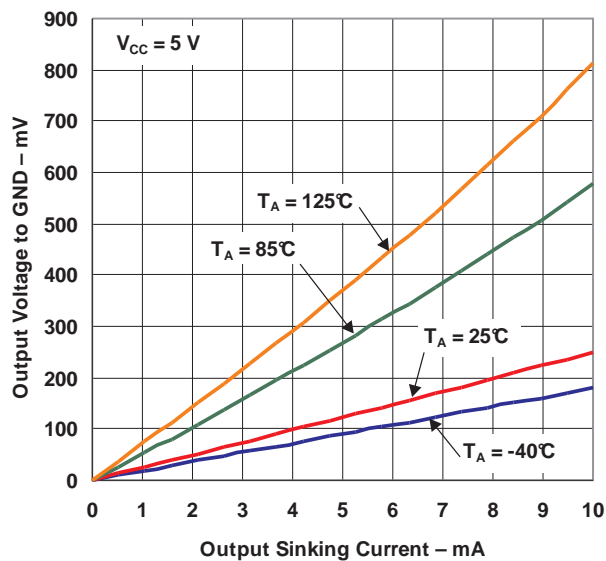
OUTPUT SINKING CURRENT
vs
SUPPLY VOLTAGE



OUTPUT VOLTAGE
vs
OUTPUT SOURCING CURRENT

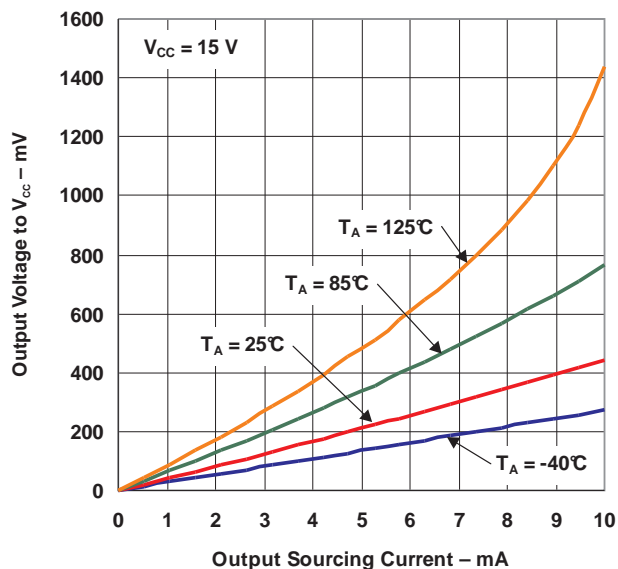


OUTPUT VOLTAGE
vs
OUTPUT SINKING CURRENT

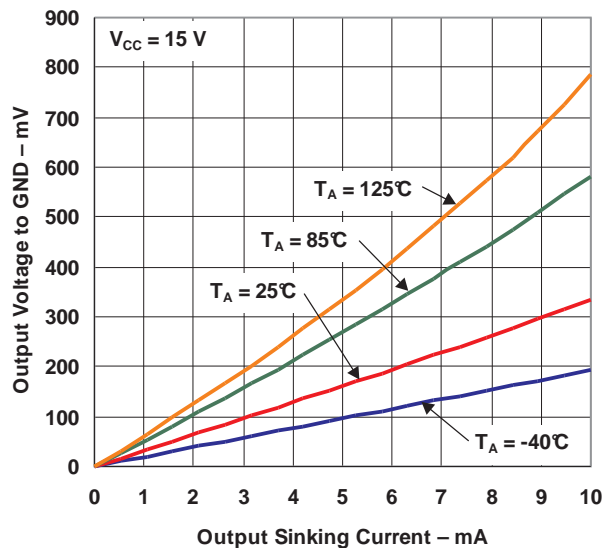


TYPICAL CHARACTERISTICS (continued)

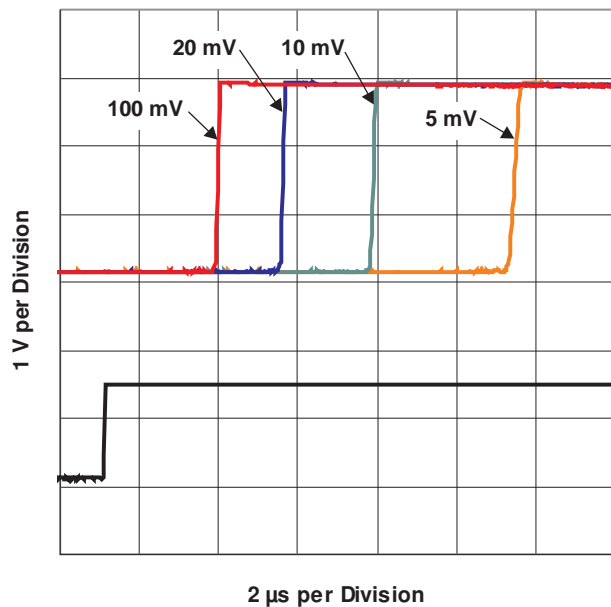
OUTPUT VOLTAGE
vs
OUTPUT SOURCING CURRENT



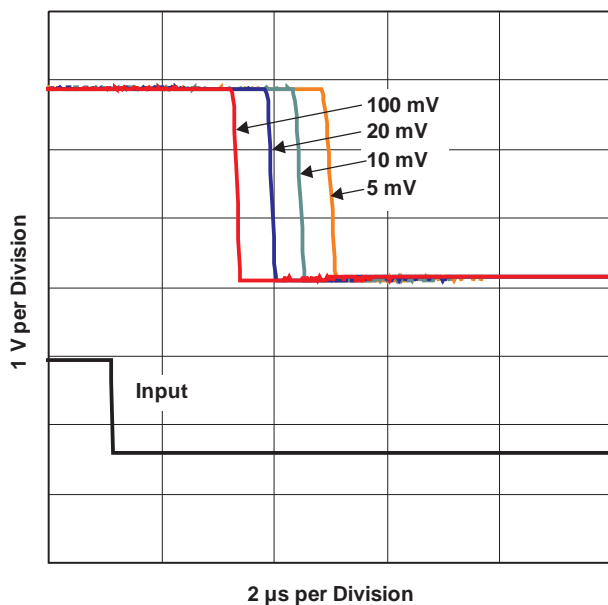
OUTPUT VOLTAGE
vs
OUTPUT SINKING CURRENT



Response Time (t_{PLH}) for Various Input Overdrives
($V_{CC} = 2.7\text{ V}$)

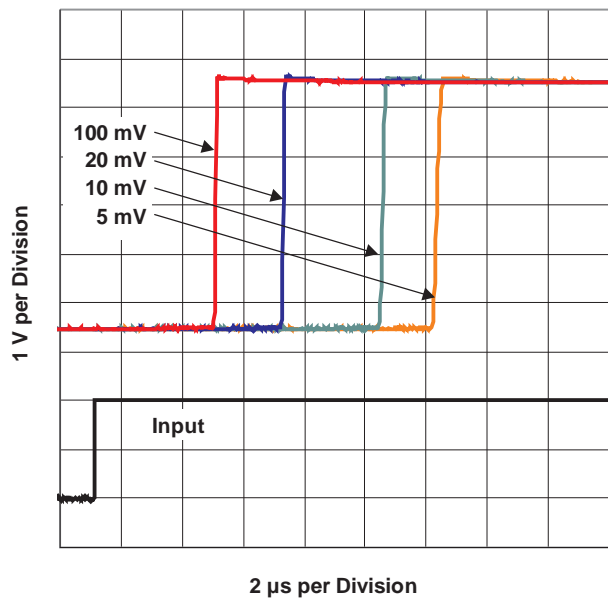


Response Time (t_{PHL}) for Various Input Overdrives
($V_{CC} = 2.7\text{ V}$)

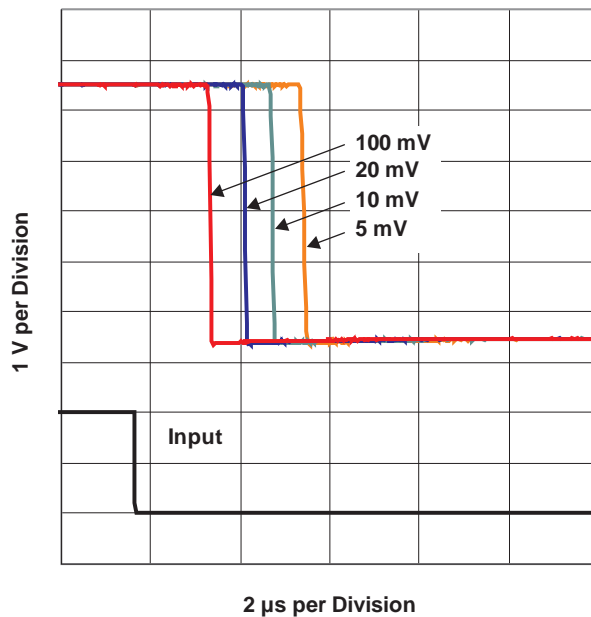


TYPICAL CHARACTERISTICS (continued)

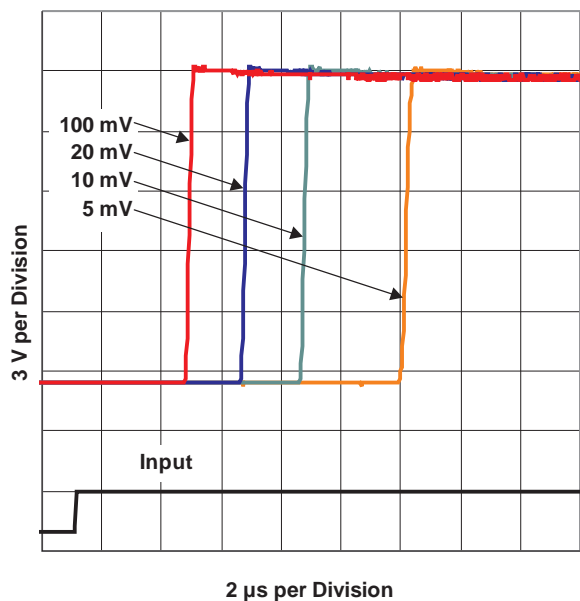
Response Time (t_{PLH}) for Various Input Overdrives
($V_{CC} = 5\text{ V}$)



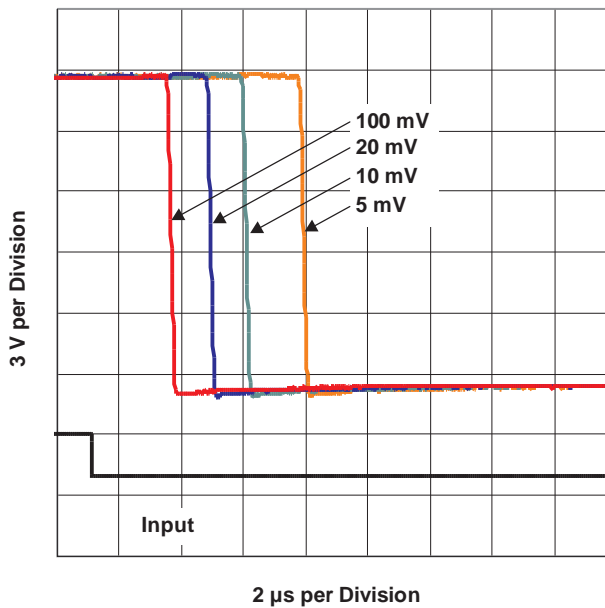
Response Time (t_{PHL}) for Various Input Overdrives
($V_{CC} = 5\text{ V}$)



Response Time (t_{PLH}) for Various Input Overdrives
($V_{CC} = 15\text{ V}$)



Response Time (t_{PHL}) for Various Input Overdrives
($V_{CC} = 15\text{ V}$)



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLV7211AID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	7211AI	Samples
TLV7211AIDBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YBNM	Samples
TLV7211AIDCKR	ACTIVE	SC70	DCK	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	Y8A	Samples
TLV7211AIDCKT	ACTIVE	SC70	DCK	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	Y8A	Samples
TLV7211AIDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	7211AI	Samples
TLV7211ID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TY7211	Samples
TLV7211IDBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YBKM	Samples
TLV7211IDCKR	ACTIVE	SC70	DCK	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	Y7A	Samples
TLV7211IDCKT	ACTIVE	SC70	DCK	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	Y7A	Samples
TLV7211IDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TY7211	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV7211AIDBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
TLV7211AIDCKR	SC70	DCK	6	3000	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
TLV7211AIDCKT	SC70	DCK	6	250	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
TLV7211AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV7211IDBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TLV7211IDCKR	SC70	DCK	6	3000	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
TLV7211IDCKT	SC70	DCK	6	250	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
TLV7211IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV7211AIDBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TLV7211AIDCKR	SC70	DCK	6	3000	202.0	201.0	28.0
TLV7211AIDCKT	SC70	DCK	6	250	202.0	201.0	28.0
TLV7211AIDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV7211IDBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TLV7211IDCKR	SC70	DCK	6	3000	202.0	201.0	28.0
TLV7211IDCKT	SC70	DCK	6	250	202.0	201.0	28.0
TLV7211IDR	SOIC	D	8	2500	340.5	338.1	20.6

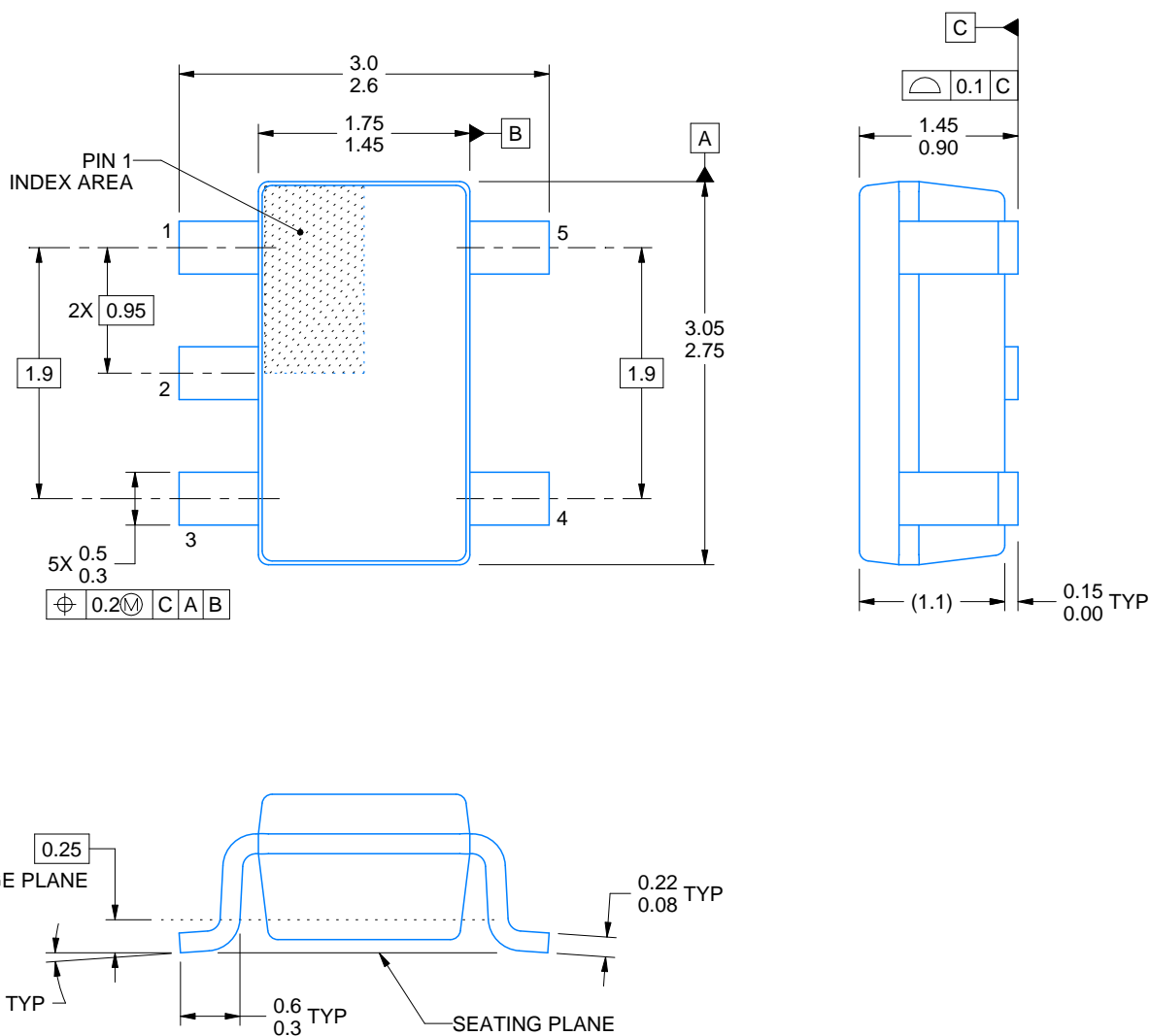


DBV0005A

PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



4214839/E 09/2019

NOTES:

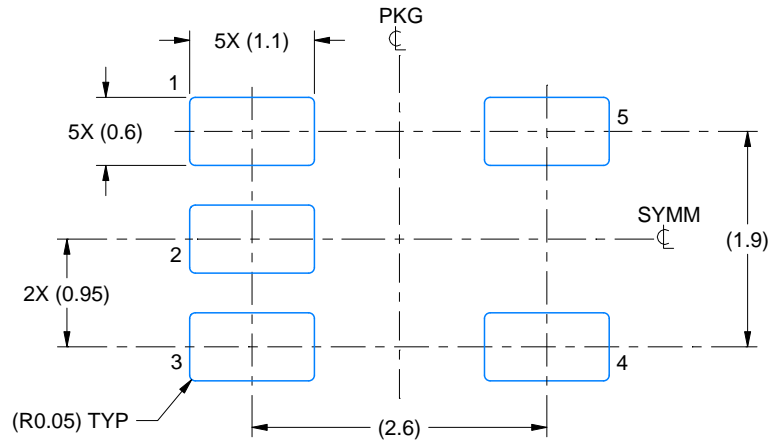
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.

EXAMPLE BOARD LAYOUT

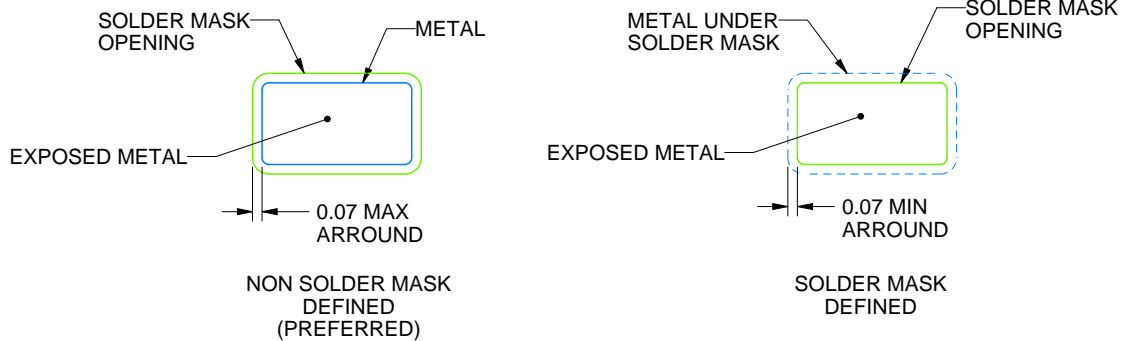
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/E 09/2019

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR

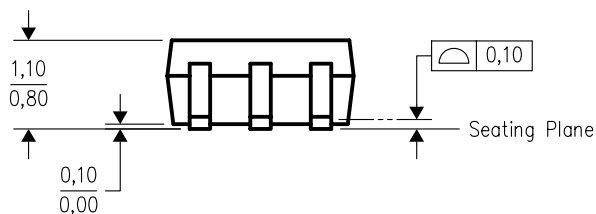


SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/E 09/2019

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.



DCK (R-PDSO-G6)

PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

D0008A**PACKAGE OUTLINE****SOIC - 1.75 mm max height**

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (www.ti.com/legal/termsofsale.html) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2020, Texas Instruments Incorporated